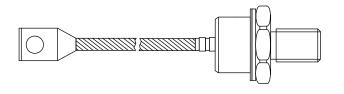


# Standard Recovery Diodes (Stud Version), 380 A



DO-205AB (DO-9)

### **FEATURES**

- Wide current range
- High voltage ratings up to 3200 V
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types
- Compression bonded encapsulations
- Lead (Pb)-free
- Designed and qualified for industrial level

PRODUCT SUMMARY				
I <sub>F(AV)</sub>	380 A			

#### **TYPICAL APPLICATIONS**

- Converters
- · Power supplies
- · Machine tool controls
- · High power drives
- Medium traction applications

24244555	TEGT COMPLETIONS	SD30		
PARAMETER	TEST CONDITIONS	16 to 20	25 to 32	UNITS
		38	80	Α
I <sub>F(AV)</sub>	T <sub>C</sub>	100	70	°C
I <sub>F(RMS)</sub>		595	425	
	50 Hz	6050		Α
I <sub>FSM</sub>	60 Hz	6335		
l <sup>2</sup> t	50 Hz	183		kA <sup>2</sup> s
J-I	60 Hz	167		KA <sup>2</sup> S
V <sub>RRM</sub>	Range	1600 to 2000	2500 to 3200	V
T <sub>J</sub>		- 40 to 180	- 40 to 150	°C

### **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS						
TYPE NUMBER	VOLTAGE CODE  VRRM, MAXIMUM REI PEAK REVERSE VC		V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	$I_{RRM} \text{ MAXIMUM}$ AT $T_J = T_J \text{ MAXIMUM}$ mA		
	16	1600	1700			
	20	2000	2100			
SD300N/R	25	2500	2600	15		
	28	2800	2900			
	32	3200	3300			

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## SD300N/R Series

## Vishay Semiconductors

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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS		SD300N/R			
PARAMETER	STIMBUL			16 to 20	25 to 32	UNITS	
	I <sub>F(AV)</sub>	190° conduction half sine ways			380	270	Α
Maximum average forward current					100	100	°C
at case temperature		180° conduction, half sine wave		300	380	Α	
					125	70	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>	DC at T <sub>C</sub> =	88 °C (02 to 2	4), T <sub>C</sub> = 91 °C (25 to 32)	595	425	
		t = 10 ms	No voltage		60	50	
Maximum peak, one-cycle forward,	Irou	t = 8.3 ms	reapplied		6335		A
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RRM</sub>		5090		
		t = 8.3  ms	reapplied	Sinusoidal half wave,	5330		
	l <sup>2</sup> t	t = 10 ms	No voltage	blied	183		- kA <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 8.3 ms	reapplied		167		
Maximum From rusing		t = 10 ms	100 % V <sub>RRM</sub>		129		
		t = 8.3 ms reapplied		118			
Maximum $I^2\sqrt{t}$ for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied		1830		kA²√s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), T <sub>J</sub> = T <sub>J</sub> maximum		0.95		V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		1.05			
Low level value of forward slope resistance	r <sub>f1</sub>	$(16.7~\%~x~\pi~x~I_{F(AV)} < I < \pi~x~I_{F(AV)}),$ $T_J = T_J~maximum$			0.75		- mΩ
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.66		1115.2	
Maximum forward voltage drop	V <sub>FM</sub>	$I_{pk} = 1180 \text{ A}, T_J = T_J \text{ maximum},$ $t_p = 10 \text{ ms sinusoidal wave}$		1.	83	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	SD30	UNITS	
		TEST CONDITIONS	16 to 20	25 to 32	UNITS
Maximum junction operating temperature range	$T_J$		- 40 to 180	- 40 to 150	°C
Maximum storage temperature range	T <sub>Stg</sub>	- 5		- 55 to 200	
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	R <sub>thJC</sub> DC operation		0.11	
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased 0.04		04	K/W
Maximum allowed mounting torque ± 10 %		Not-lubricated threads 27		7	Nm
Approximate weight		250		50	g
Case style		ee dimensions (link at the end of datasheet) DO-205AB (DO		9)	



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△R <sub>thJC</sub> CONDUCTION						
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS		
180°	0.019	0.013				
120°	0.023	0.023				
90°	0.028	0.030	$T_J = T_J \text{ maximum}$	K/W		
60°	0.042	0.044				
30°	0.073	0.074				

#### Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

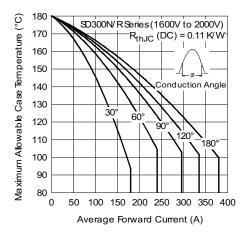


Fig. 1 - Current Ratings Characteristics

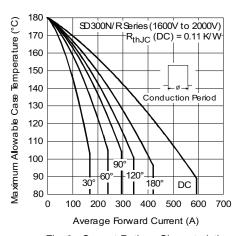


Fig. 2 - Current Ratings Characteristics

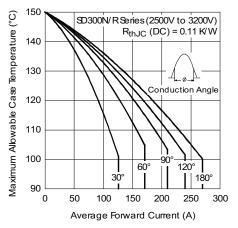


Fig. 3 - Current Ratings Characteristics

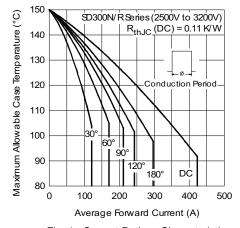


Fig. 4 - Current Ratings Characteristics

## Standard Recovery Diodes (Stud Version), 380 A



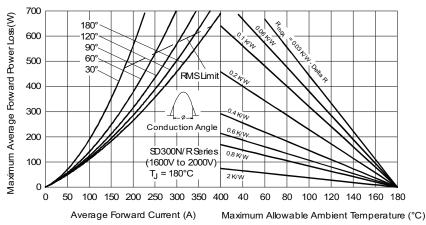


Fig. 5 - Forward Power Loss Characteristics

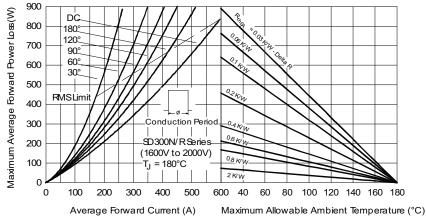


Fig. 6 - Forward Power Loss Characteristics

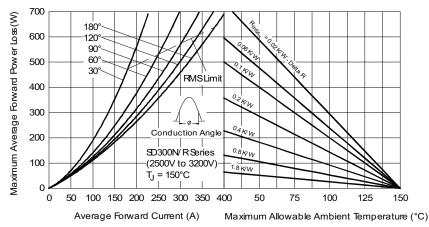


Fig. 7 - Forward Power Loss Characteristics

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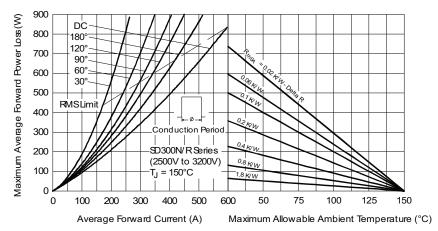


Fig. 8 - Forward Power Loss Characteristics

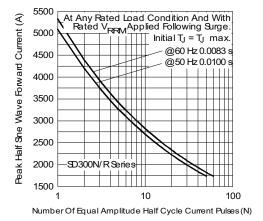


Fig. 9 - Maximum Non-Repetitive Surge Current

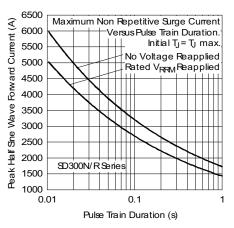


Fig. 10 - Maximum Non-Repetitive Surge Current

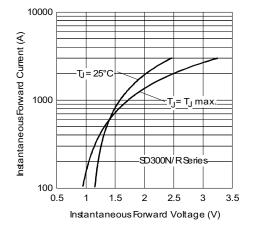


Fig. 11 - Forward Voltage Drop Characteristics

### Standard Recovery Diodes (Stud Version), 380 A



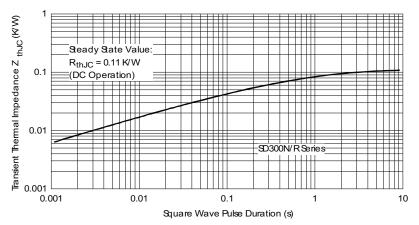
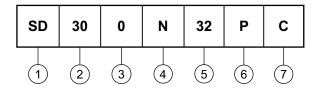


Fig. 12 - Thermal Impedance  $Z_{\text{thJC}}$  Characteristics

#### **ORDERING INFORMATION TABLE**

Device code



- Diode
- Essential part number
- 0 = Standard recovery
- N = Stud normal polarity (cathode to stud)
  - R = Stud reverse polarity (anode to stud)
- Voltage code x 100 = V<sub>RRM</sub> (see Voltage Ratings table)
- P = Stud base DO-205AB (DO-9) 3/4" 16UNF-2A
- C = Ceramic housing

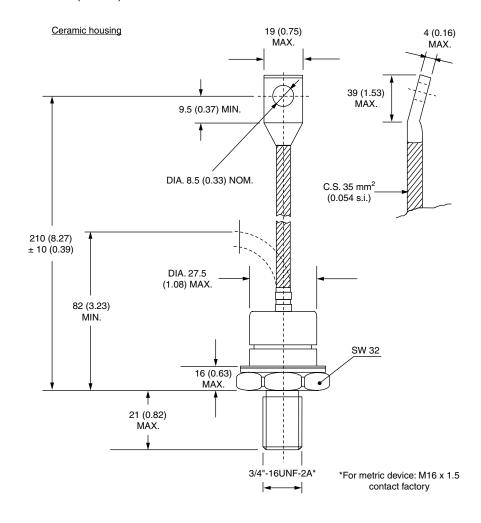
For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS			
Dimensions	http://www.vishay.com/doc?95301		

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## **DO-205AB (DO-9)**

### **DIMENSIONS** in millimeters (inches)





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Vishay

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